



3.3V, PCI Express® 3.0, 1-Lane, 2-Channel, 8Gbps, 2:1 Mux/DeMux Switch w/ Single Enable

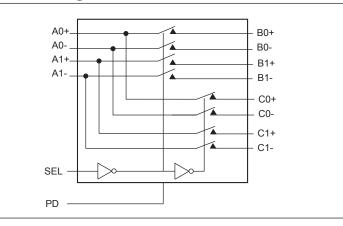
Features

- → 2-Differential Channel, 2:1 Mux/DeMux
- → PCI Express[®] 3.0 performance, 8.0Gbps
- ➔ Bidirectional operation
- → 3dB Bandwidth: 8.1GHz
- → Low Bit-to-Bit Skew, 10ps max
- → Low Channel-to-Channel skew: 20ps max
- → Low Insertion Loss: -1.7dB @4GHz (8.0Gbps)
- → Low Return Loss: -13.5dB @4GHz (8.0Gbps)
- → Low Crosstalk: -32dB@4GHz (8.0Gbps)
- → Low Off Isolation: -21dB@4GHz (8.0Gbps)
- → Supply Voltage: $3.3V \pm 10\%$
- → Industrial Temperature Range: -40°C to 85°C
- → Low Current: 0.2mA typ.
- → Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- → Halogen- and Antimony-Free. "Green" Device (Note 3)
- → For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative.

https://www.diodes.com/quality/product-definitions/

- → Packaging (Pb-free & Green):
 - 20-contact TQFN (2.5 × 4.5mm)
 - 18 contact, X2QFN(XUA18), 2x2mm

Block Diagram



Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Description

The PI3PCIE3212 is a PCIe Gen3.0, 8Gbps, 4-to-2 differential, bidirectional-channel multiplexer/demultiplexer switch. This product is ideal for PCI Express[®] 3.0 signal switching at 8.0Gbps due to its low bit-to-bit skew, high channel-to-channel noise isolation, and bandwidth.

Applications

The PI3PCIE3212 switches a PCI Express 3.0 lane output between two PCI Express lane inputs. Applications include NBs, PCs, servers, and other embedded devices. The PI3PCIE3212 can route PCI Express 3.0, DP1.2, USB3.0, SAS2.0, SATA3.0, XAUI, RXAUI signals with low signal attenuation.

Truth Table

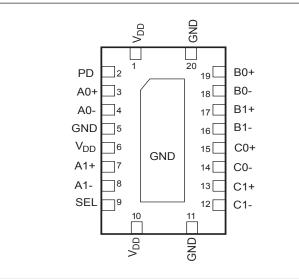
Function	SEL	PD
A to B	L	L
A to C	Н	L
All ports Hi-Z, IC Power Down	Х	Н

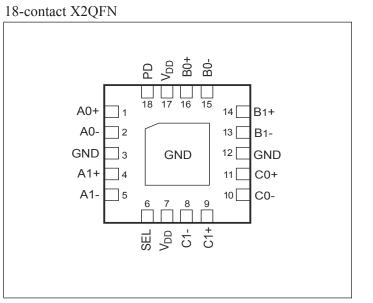




Pin Configuration (Top-side view)

20-contact TQFN





Pin Description

20-TQFN Pin #	18-X2QFN Pin #	Pin Name	I/O	Description		
3	1	A0+	LO	Simulation Changel 0 Dept 4		
4	2	A0-	I/O	Signal I/O, Channel 0, Port A		
7	4	A1+	UO	Signal I/O. Changed 1. Dogt 4		
8	5	A1-	I/O	Signal I/O, Channel 1, Port A		
19	16	B0+	L/O	Simulation Changed & Dept D		
18	15	В0-	I/O	Signal I/O, Channel 0, Port B		
17	14	B1+	LO	Grand I/O. Changed I. Dect D.		
16	13	B1-	I/O	Signal I/O, Channel 1, Port B		
15	11	C0+	LO	Simulation Changel & Dect C		
14	10	C0-	I/O	Signal I/O, Channel 0, Port C		
13	9	C1+	LO	Grand I/O. Changed I. Dect. C.		
12	8	C1-	I/O	Signal I/O, Channel 1, Port C		
9	6	SEL	Ι	Operation mode Select (when SEL=0: A→B, when SEL=1: A→C		
2	18	PD	Ι	PD = 1, Power down is enabled. Please see Truth Table.		
1, 6, 10	7, 17	V _{DD}	Pwr	3.3V ±10% Positive Supply Voltage		
5, 11, 20	3, 12, Center Pad	GND	Pwr	Power ground		



Note:



PI3PCIE3212

Maximum Ratings

(Above which useful life may be impaired. For user guidelines, not tested.)

Storage Temperature	65°C to +150°C
Supply Voltage to Ground Potential	0.5V to +4.6V
Channel DC Input Voltage	–0.5V to 1.5V
DC Output Current	120mA
Power Dissipation	0.5W
SEL/PD DC Input Voltage	0.5V to 4.6V
Junction Temperature	125°C
ESD (HBM)	2kV

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Electrical Characteristics

Recommended Operating Conditions

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
V _{DD}	3.3V Power Supply		3.0	3.3	3.6	V
I _{DD}	Total current from V _{DD} 3.3V supply	SEL = OV or V_{DD}		0.2	1	mA
I _{DD_PD}	Power down current	PD = 1		20	40	μΑ
V _{I/O} -DIF	Differential Voltage (differential pins)	Differential Voltage (differential pins)			1.6	V _{ppd}
V _{I/O-CM}	Common Mode Voltage (differential pins)		0		0.8	V
T _A	Operating temperature range		-40		85	°C

DC Electrical Characteristics for Switching over Operating Range

Parameters	Description	Test Conditions ⁽¹⁾	Min.	Typ. ⁽¹⁾	Max.	Units
V _{IH} - sel, pd	Input HIGH Voltage, SEL, PD Input		2		3.6	
V _{IL} - _{SEL} , PD	Input LOW Voltage, SEL, PD Input		0		0.8	V
V _{IK}	Clamp Diode Voltage	V_{DD} = Max., I_{IN} = -18mA		-0.7	-1.2	
IIH	Input HIGH Current, SEL, PD	$V_{DD} = Max., V_{IN} = V_{DD}$			±5	
IIL	Input LOW Current, SEL, PD	$V_{DD} = Max., V_{IN} = 0V$			±5	μΑ
IIH	Input HIGH Current, A _X , B _X , C _X	V_{DD} = Max., V_{IN} = 1.5V	-10		+10	
IIL	Input LOW Current, A _X , B _X , C _X	$V_{DD} = Max., V_{IN} = 0V$	-10		+10	μA
IOZH	HighZ HIGH Current, B _X , C _X	V _{DD} = Max., V _{IN} = 1.5V	-10		+10	μΑ
I _{OZL}	HighZ LOW Current, B _X , C _X	$V_{DD} = Max., V_{IN} = 0V$	-10		+10	μΑ

Note:

1. Typical values are at V_{DD} = 3.3V, T_A = 25°C ambient and maximum loading.





Switching Characteristics

Parameters	Description	Test Conditions	Min.	Тур.	Max.	Units
tpZH, tpZL	Line Enable Time - SEL to A_N , B_N , C_N			25	30	
tpHZ, tPLZ	Line Disable Time - SEL to A_N , B_N , C_N			5	25	ns
t _{PLH}	Propagation Delay, LOW to HIGH		17		36	ps
t _{PHL}	Propagation Delay, HIGH to LOW		21		39 ps	
t _{b-b}	Bit-to-bit skew within the same differential pair			5	10	ps
t _{ch-ch}	Channel-to-channel skew				20	ps

Dynamic Electrical Characteristics

Parameter	Description	Test Conditions	Min.	Typ. ¹	Max.	Units
		f = 100MHz		-0.4		
		f = 100MHz-1.25GHz		-0.6		
DDIL ^(2,3)	Differential Insertion Loss	f = 1.25GHz-2.5GHz		-1.0		dB
	$(V_{\rm IN} = -10 dBm, DC = 0V)$	f = 2.5 GHz - 4 GHz		-1.7		
		f = 5GHz		-2.1		
		f = 100MHz		-59		
DDIL _{OFF} ^(2,3) Differential	Differential Off Ladation	f = 100MHz-1.25GHz		-37		תנ
	Differential Off Isolation	f = 1.25GHz-2.5GHz		-27		dB
		f = 2.5 GHz - 4 GHz		-21		
		f = 100MHz		-27		dB
DDRL ⁽²⁾		f = 100MHz-1.25GHz		-23.3		
DDRL ^{-/}	Differential Return Loss	f = 1.25GHz-2.5GHz		-23.3		
		f = 2.5 GHz - 4 GHz		-13.5		
	Near End Crosstalk	f = 100MHz		-57		
DDNEXT ^(2,3)		f = 100MHz-1.25GHz		-38		10
		f = 1.25GHz-2.5GHz		-33		dB
		f = 2.5 GHz - 4 GHz		-32		
BW	-3dB Bandwidth			8.1		GHz

Notes:

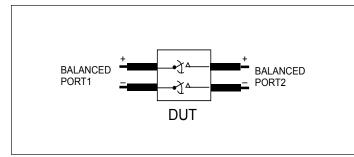
1. Guaranteed by design. Typical values are at $V_{DD} = 3.3V$, $T_A = 25^{\circ}C$ ambient and maximum loading.

S parameters are measured with our evaluation board made with Rogers (R04350) material. Trace width is 30 mil, length 540 mil, trace impedance is 50 Ohm 2. (+/5%) and total insertion loss of the trace is 0.5dB@4GHz.

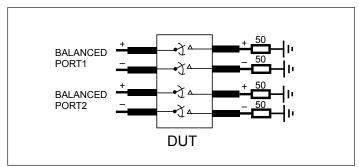
3. Measurement done with fixture deembedding.



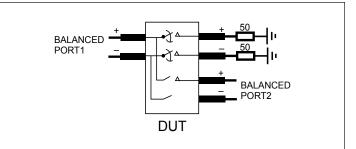




Diff. Insertion Loss and Return Test Circuit



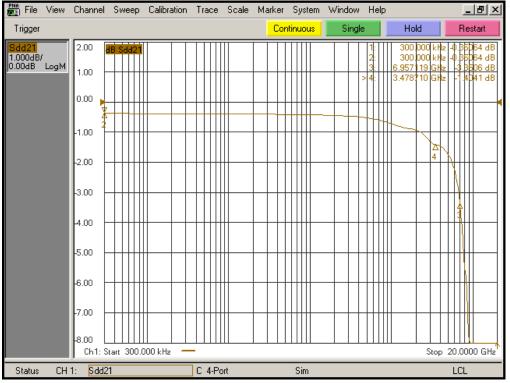
Diff. Near End Xtalk Test Circuit



Diff. Off Isolation Test Circuit







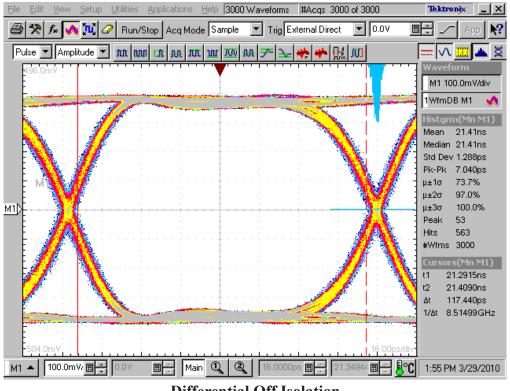
Differential Insertion Loss



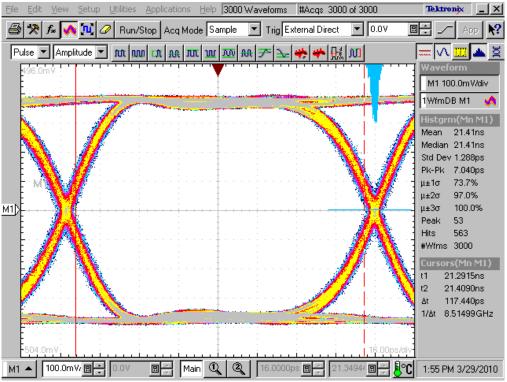
Differential Return Loss







Differential Off Isolation

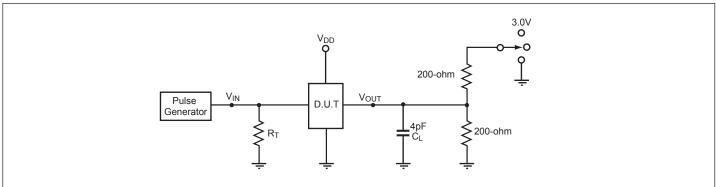


Differential Crosstalk





Test Circuit for Electrical Characteristics⁽¹⁻⁵⁾



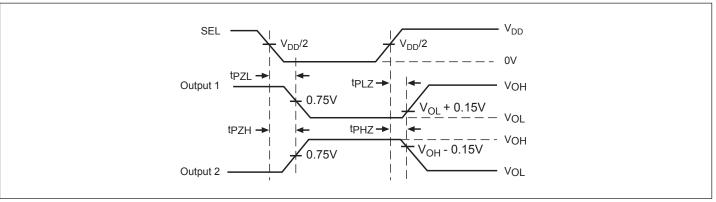
Notes:

- C_L = Load capacitance: includes jig and probe capacitance. 1.
- 2. R_T = Termination resistance: should be equal to Z_{OUT} of the Pulse Generator
- Output 1 is for an output with internal conditions such that the output is low except when disabled by the output control. 3. Output 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- 4. All input impulses are supplied by generators having the following characteristics: PRR \leq MHz, Z_O = 50 Ω , t_R \leq 2.5ns, t_F \leq 2.5ns,
- The outputs are measured one at a time with one transition per measurement. 5.

Switch Positions

Test	Switch
t _{PLZ} , t _{PZL}	3.0V
t _{PHZ} , t _{PZH}	GND

Switching Waveforms

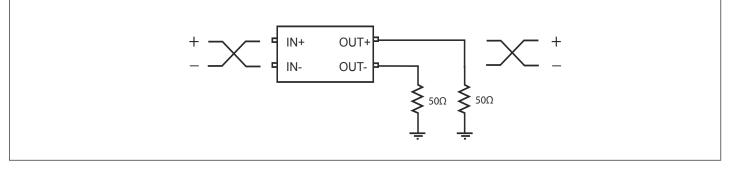


Voltage Waveforms Enable and Disable Times

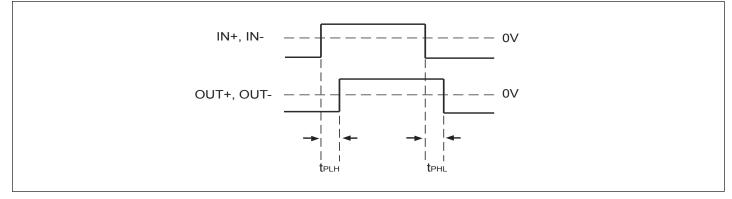




Test Circuit for Propagation Delay



Differential Input/Output Signal Waveform



Part Marking

ZB Package



YY: Year WW: Workweek 1st X: Assembly Code 2nd X: Fab Code

XUA Package

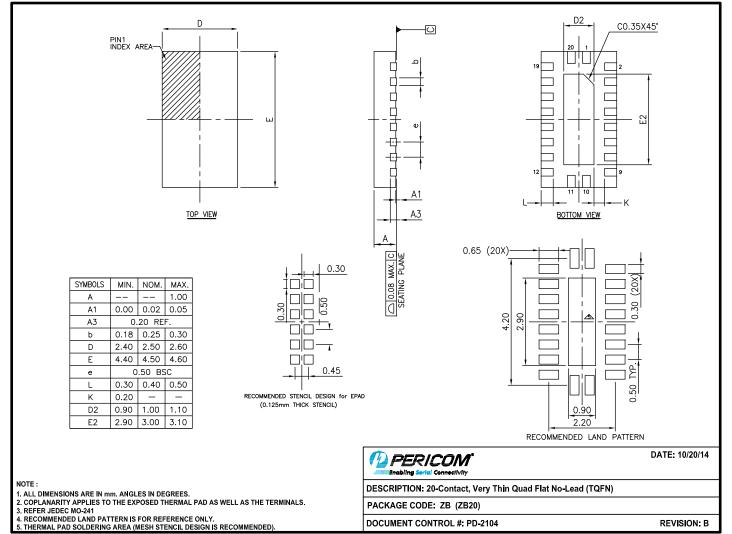


ZT: PI3PCIE3212 Y: Year W: Workweek





Packaging Mechanical: 20-TQFN (ZB)

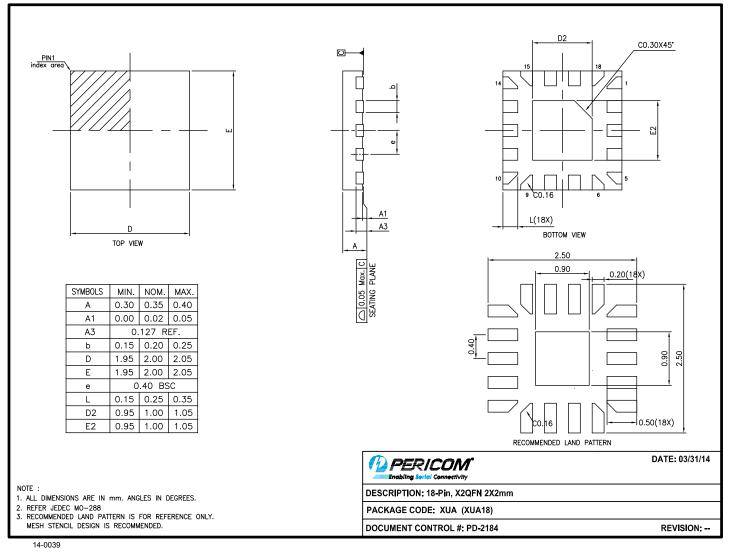


14-0265





Packaging Mechanical: 18-XUA (X2QFN)



For latest package info.

please check: http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/

Ordering Information

Ordering Code	Package Code	Package Type
PI3PCIE3212ZBEX	ZB	20-contact, Very Thin Quad Flat No-Lead (TQFN)
PI3PCIE3212XUAEX	XUA	18-Pin, 2x2mm (X2QFN)

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

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4. E = Pb-free and Green

5. X suffix = Tape/Reel





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